

Supporting Information

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Rationalizing Electron–Phonon Interactions and Hot Carriers Cooling in 2D to 3D Metal Halide Perovskites

Arup Mahata*, Edoardo Mosconi, Daniele Meggiolaro*, Simona Fantacci and Filippo De Angelis*

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Text S1. Computational Details

The first-principles calculations based on density functional theory (DFT) are carried out as implemented in the PWSCF Quantum-Espresso package.¹ Geometry optimization is performed using GGA-PBE² level of theory, and the electrons-ions interactions were described by ultrasoft pseudo-potentials with electrons from I 5s, 5p; N, C 2s, 2p; H 1s; Pb 6s, 6p, 5d; shells explicitly included in calculations. The experimental cell parameters have been used in all the cases for the *a* and *b* directions of the lattice, whereas half of the cell parameter of *c* is consider in some cases, where two quantum wells are present in the experimental crystal structures. The cell parameters for MAPbI₃, BA-n1, PEA-n1, BA-n3, PEA-n3, and OCTA-n1 have been taken from Ref³, Ref⁴, Ref⁵, Ref⁶, Ref⁷, Ref⁸, respectively. Geometry optimizations for $2 \times 2 \times 1$ supercell are performed with a k-point sampling⁹ of $4 \times 4 \times 2$, along with plane-wave basis set cutoffs for the smooth part of the wave functions and augmented electronic density expansions of 25 and 200 Ry, respectively.

Electronic band gap is calculated by single-point hybrid calculations including spin-orbit coupling (SOC). These are conducted using the modified version of the HSE06 functional¹⁰ including 43% Hartree–Fock exchange as in Ref¹¹ with norm-conserving pseudo-potentials with electrons from I 5s, 5p; N, C 2s, 2p; H 1s; Pb 5s, 5p, 6s, 6p, 5d; shells are explicitly included in calculations, with $2\times 2\times 1$ k-point sampling with plane-wave basis set cutoffs for the

smooth part of the wave functions and augmented electronic density expansions of 40 and 80Ry, respectively.

Frequency calculations have been performed by DFPT and by using PBE functional and ultrasoft pseudopotentials with a cutoff on the wavefunction of 25 Ry (200 Ry on the charge density) and uniform $4\times4\times2$ grid of k-points in the Brillouin zone. Phonon DOS has been plotted from the interatomic force constant in real space, which was calculated from the dynamical matrices produced at Γ point followed by their Fourier-transformation. For MAPbI₃, the phonon DOS is reported for $2\times2\times2$ grid of k-points.



Figure S1. e-ph interaction of MAPbI₃ for the band edge states at different q-points in GGA-PBE level of theory. Left and right panels represent the e-ph coupling at VBM and CBM, respectively.



Figure S2. e-ph interaction of MAPbI₃ for the band edge state at Γ q-point at different level of theory



Figure S3. Phonon DOS and vibrations having significant e-ph coupling of (a) PEA-n3 and (b) BA-n3



Figure S4. Atomic displacements of the inorganic moiety for each normal mode of MAPbI₃.



Figure S5. Wave function localization for the electron (upper panel) and hole (lower panel) polaron of (a) BA-n1 and (b) BA-n3.



Figure S6. Wave function localization for the electron (upper panel) and hole (lower panel) polaron of (a) PEA-n1, (b) PEA-n3 and, (c) MAPbI₃.

Table S1. Cumulative e-ph coupling of two higher energy bands above CBM (~1.5, 2.0 and 0.5 eV energy window for 3D, 2D and 2D-n3 phases, respectively) in different frequency regions for the various systems.

Systems		Energy (eV)	e-ph coupling (meV) in different frequency (cm ⁻¹) regions			Ratio
			0-60	60-120	120-200	
	CBM	0.00	78	82	0	9:10:0
MAPbI ₃	CBM1	0.74	26	24	0	10:9:0
	CBM2	1.49	36	36	0	10:10:0
	Total		140	142	0	10:10:0
	CBM	0.00	54	404	0	1:10:0
PEA ₂ PbI ₄	CBM1	1.27	42	226	0	2:10:0
	CBM2	1.99	82	642	0	1:10:0
	Total		178	1272	0	1:10:0
	CBM	0.00	66	350	4	2:10:0
BA ₂ PbI ₄	CBM1	1.29	52	190	6	3:10:0
	CBM2	1.93	20	1170	2	0:10:0
	Total		138	1710	12	1:10:0
	CBM	0.00	78	134	0	6:10:0
OCTA ₂ PbI ₄	CBM1	1.18	38	90	0	4:10:0
	CBM2	1.93	68	532	0	1:10:0
	Total		184	756	0	2:10:0
	СВМ	0.00	62	104	20	6:10:1
$(\mathbf{BA})_2(\mathbf{MA})_2\mathbf{Pb}_3\mathbf{I}_{10}$	CBM1	0.24	40	104	6	4:10:0
	CBM2	0.45	124	78	8	10:6:0
	Total		226	286	34	8:10:1

Table S2. Cumulative e-ph coupling of five lower energy bands (~1.0 eV energy window for all phases) below VBM in different frequency regions for the various systems.

Systems		Energy (eV)	e-ph coupling (meV) in different frequency (cm ⁻¹) regions			
						Ratio
			0-60	60-120	120-200	
	VBM	0.00	124	18	2	10:1:0
MAPbI ₃	VBM-1	0.39	44	20	4	10:4:1
	VBM-2	0.98	40	40	10	10:10:2
	VBM-3	1.04	40	22	0	10:5:0
	VBM-4	1.07	16	16	16	10 : 10 : 10
	VBM-5	1.20	46	32	20	10:7:4
	Total		310	148	52	10:5:2
	VBM	0.00	86	226	2	4:10:0
PEA ₂ PbI ₄	VBM-1	0.76	30	154	0	2:10:0
	VBM-2	0.95	64	192	4	3:10:0
	VBM-3	0.98	60	126	2	10:5:0
	VBM-4	0.99	30	38	0	8:10:0
	VBM-5	1.07	48	38	0	10:8:0
	Total		318	774	8	4:10:0
	VBM	0.00	74	366	8	2:10:0
BA ₂ PbI ₄	VBM-1	0.81	38	308	8	1:10:0
	VBM-2	0.89	66	194	10	3:10:0
	VBM-3	0.90	44	92	10	5:10:1
	VBM-4	1.00	30	92	4	3:10:0
	VBM-5	1.04	14	60	2	2:10:0
	Total		266	1112	42	2:10:0
	VBM	0.00	128	204	0	6:10:0
OCTA ₂ PbI ₄	VBM-1	0.62	48	132	0	3:10:0
	VBM-2	0.80	74	118	0	6:10:0
	VBM-3	0.82	42	64	0	6:10:0
	VBM-4	0.93	20	44	0	4:10:0
	VBM-5 & CBM	0.99	32	58	0	5:10:0
	Total		344	620	0	5:10:0
	VBM	0.00	130	62	16	10:5:1
(BA)2(MA)2Pb3I10	VBM-1	0.31	62	72	32	9:10:4
	VBM-2	0.34	84	82	54	10:10:6
	VBM-3	0.85	34	36	2	10:10:0
	VBM-4	0.97	24	34	6	7:10:2
	VBM-5	1.00	18	22	8	8:10:4
	Total		352	308	118	10:9:3

Systems	Cell Parameters (Å)	References
MAPbI ₃	8.849 0.000 0.00	Ref ³
	0.000 8.849 0.000	
	0.000 0.000 12.642	
BA-n1	8.8512 0.0000 0.0000	Ref ⁴
	0.0000 8.6543 0.0000	
	0.0000 0.0000 13.86765	
PEA-n1	8.7398 0.0000 0.0000	Ref ⁵
	0.0152 8.7402 0.0000	
	1.0438 1.5916 16.5156	
BA-n3	8.9274 0.0000 0.0000	Ref ⁶
	0.0000 25.9794 0.0000	
	0.0000 0.0000 8.8776	
PEA-n3	30.69 0.000	Ref ⁷
	0.000	
	0.000 8.9 0.000	
	-0.43481 0.000 9.0195	
OCTA-n1	8.4541 0.0000 0.0000	Ref ⁸
	0.0000 8.9916 0.0000	
	-2.0565 0.0000 18.6248	

Table S3. Cell parameters considered in this paper and the corresponding experimental references.

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